RT1N137L

TRANSISTOR WITH RESISTOR FOR SWITCHING APPLICATION SILICON NPN EPITAXIAL TYPE

DESCRIPTION

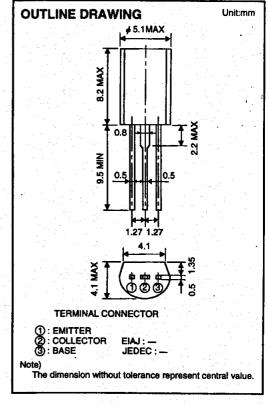
(RT1N137L is a one chip transistor with built-in bias resistor, PNP type is RT1P137L.

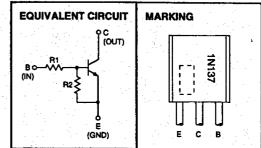
FEATURE

- Built-in bias resistor (R1=1kΩ,R2=22kΩ)
- ●High collector current lc=1A
- ●Low VcE(sat) VcE(sat)=0.3Vmax (@1c=300mA,IB=3mA)
- ●High collector dissipation Pc=900mW

APPLICATION

inverted circuit, switching circuit, interface circuit, driver circuit.





MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Ratings	Unit
Vcso	Collector to Base voltage	40	V
VEBO	Emitter to Base voltage	6	V
VCEO	Collector to Emitter voltage	40	V
lc	Collector current	1	A
Ісм	Peak Collector current	2	A
Pc	Collector dissipation(Ta=25°C)	900	mW
Tj	Junction temperature	+150	c
Tstg	Storage temperature	-55 to +150	°C

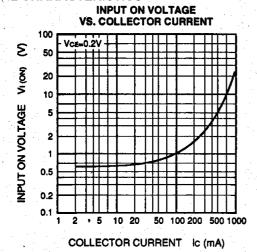
ELECTRICAL CHARACTERISTICS (Ta=25°C)

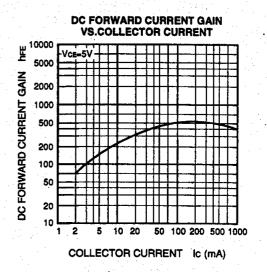
Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	O INC
V(BR)CEO	C to E break down voltage	Ic=1mA,RBE=∞	- 40			V
Ісво	Collector cut off current	Vcb=40V,IE=0		- :	0.1	μΑ
hFE	DC forward current gain	VcE=5V,lc=100mA	100			
VCE(sat)	C to E saturation voltage	Ic=300mA,IB=3mA		0.1	0.3	V
VI(ON)	Input on voltage	Vce=0.2V,lc=300mA		2.3	4.0	V
VI(OFF)	Input off voltage	VcE=5V,lc=100 μA	0.4	0.5		V
Rı	Input resistor		0.7	1.0	1.3	kΩ
R2/R1	Resistor ratio		20	22	24	
fr	Gain band width product	VcE=6V,IE=-10mA		150		MHz

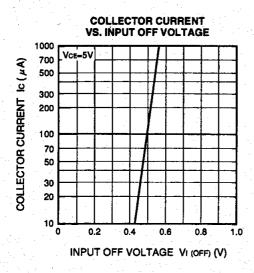
RT1N137L

TRANSISTOR WITH RESISTOR FOR SWITCHING APPLICATION SILICON NPN EPITAXIAL TYPE

TYPICAL CHARACTERISTICS









http://www.idc-com.co.jp 6-41, TSUKUBA, ISAHAYA, NAGASAKI, 854-0065, JAPAN

Keep safety in your circuit designs!

Isahaya Electronics Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of non-flammable material or (iii) prevention against any malfunction or mishap.

Notes regarding these materials

•These materials are intended as reference to assist out customers in the selection of the Isahaya semiconductor product best suited to the customer's application, they do not convey any license under any intellectual property rights, or any other rights, belonging to Isahaya Electronics Corporation or a third party.

Isahaya Electronics Corporation assumes no responsibility for any damage, or infringement of any third-party rights, originating in the use of any product data, diagrams, charts or circuit application examples contained in the materials.

All information contained in these materials, including product data, diagrams and charts, represent information on products at the time of publication of these materials, and are subject to change by Isahaya Electronics Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact Isahaya Electronics Corporation or authorized Isahaya Semiconductor product distributor for the latest product information before purchasing a product listed herein.

The prior written approval of Isahaya Electronics Corporation is necessary to reprint or reproduce in whole or in part these materials.

If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or reexport contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited.

Please contact Isahaya Electronics Corporation or an authorized Isahaya Semiconductor product distributor for further details on these materials or the products contained therein.